

ABSTRACT OF THE DISCLOSURE

An active matrix display device is provided a display area including a set of pixel regions each having a first thin-film transistor, and a driving circuit forming area located outside the display area and having second thin-film transistors. A gate electrode of the first thin-film transistor is made of a material different than a gate signal line and has a portion that is directly laid on or under the gate signal line to establish electrical connection. A gate electrode of each of the second thin-film transistors is made of a material different than a wiring layer or electrode to be connected to it and has a portion that is directly laid on or under the wiring layer or electrode to establish electrical connection. The gate electrode of the first thin-film transistor is made of the same material as that of each of the second thin-film transistors. The gate signal line is made of the same material as the wiring layer or electrode.

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